

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of :  
 :  
Ôka et al. :  
 : Group Art Unit: Unassigned  
Application S/N: New Application :  
 : Examiner: Unassigned  
Filed: Concurrently herewith :  
 :  
For: CRYSTALLINE SILICON THIN FILM SEMICONDUCTOR DEVICE,  
CRYSTALLINE SILICON THIN FILM PHOTOVOLTAIC DEVICE, AND PROCESS  
FOR PRODUCING CRYSTALLINE SILICON THIN FILM SEMICONDUCTOR DEVICE

PRELIMINARY AMENDMENT

Honorable Assistant  
Commissioner  
for Patents  
Washington, DC 20231

Sir:

This preliminary amendment is directed to the above-referenced application. Prior to examination, please amend the application as follows:

IN THE CLAIMS

Please amend claims 9-10 and 16 as follows:

SUB C17  
9. The crystalline silicon thin film semiconductor device according to claim 6, wherein the fourth polycrystalline silicon layer has the same crystallographic orientation as the third polycrystalline silicon layer.